

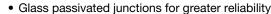
# Power Modules, Passivated Assembled Circuit Elements, 40 A



PACE-PAK (D-19)

PRODUCT SUMMARY					
Io	40 A				
Type	Modules - Thyristor, Standard				
Package PACE-PAK (D-19)					
Circuit	Single phase, hybrid bridge common cathode, Single phase, hybrid bridge doubler connection, Single phase, all SCR bridge				

#### **FEATURES**





- · Electrically isolated base plate
- Available up to 1200 V<sub>RRM</sub>/V<sub>DRM</sub>
- High dynamic characteristics
- · Wide choice of circuit configurations
- · Simplified mechanical design and assembly
- UL E78996 approved
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION**

The VS-P400 series of integrated power circuits consists of power thyristors and power diodes configured in a single package. With its isolating base plate, mechanical designs are greatly simplified giving advantages of cost reduction and reduced size.

Applications include power supplies, control circuits and battery chargers.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
Io	80 °C	40	Α			
I <sub>TSM</sub> ,	50 Hz	385	۸			
I <sub>FSM</sub>	60 Hz	400	Α			
l <sup>2</sup> t	50 Hz	745	A2a			
1-1	60 Hz	680	A <sup>2</sup> s			
I <sup>2</sup> √t		7450	A <sup>2</sup> √s			
V <sub>RRM</sub>	Range	400 to 1200	V			
V <sub>ISOL</sub>		2500	V			
T <sub>J</sub>		40 to 105	°C			
T <sub>Stg</sub>		-40 to 125	C			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE AND PEAK OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> MAXIMUM mA			
VS-P401, VS-P421, VS-P431	400	500				
VS-P402, VS-P422, VS-P432	600	700				
VS-P403, VS-P423, VS-P433	800	900	10			
VS-P404, VS-P424, VS-P434	1000	1100				
VS-P405, VS-P425, VS-P435	1200	1300				



ON-STATE CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum DC output current	I-	In Full bridge circuits			40	Α
at case temperature	I <sub>O</sub>	ruii briuge	Circuits		80	°C
		t = 10 ms	No voltage		385	
Maximum peak, one-cycle non-repetitive on-state or	I <sub>TSM</sub> ,	t = 8.3  ms	reapplied		400	Α
forward current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		325	A
		t = 8.3  ms	reapplied	Sinusoidal half wave,	340	
		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	745	
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	t = 8.3  ms	reapplied		680	A <sup>2</sup> s
Maximum i-t for fusing	i-t	t = 10 ms	100 % V <sub>RRM</sub>		530	
		t = 8.3  ms	reapplied		480	
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied $1^2$ t for time tx = $1^2 \sqrt{t} \cdot \sqrt{t}x$		7450	A <sup>2</sup> √s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.83	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.03	V	
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$ ), $T_J = T_J$ maximum	9.61	mΩ
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)})$	$(J)$ , $T_J = T_J$ maxim	num	7.01	11122
Maximum on-state voltage drop	$V_{TM}$	$I_{TM} = \pi \times I_{T(AV)}$ $T_J = 25  ^{\circ}C$		1.4	٧	
Maximum forward voltage drop	$V_{FM}$	$I_{FM} = \pi \times I_{F(AV)}$ $T_J = 25  ^{\circ}C$		1.4	٧	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	$T_{J} = 125~^{\circ}\text{C}$ from 0.67 $V_{DRM}$ $I_{TM} = \pi \times I_{T(AV)}, I_{g} = 500$ mA, $t_{r} < 0.5~\mu\text{s}, t_{p} > 6~\mu\text{s}$		200	A/µs	
Maximum holding current	I <sub>H</sub>			130	mA	
Maximum latching current	ΙL	T <sub>J</sub> = 25 °C anode supply = 6 V, resistive load		250	IIIA	

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J$ = 125 °C, exponential to 0.67 $V_{DRM}$ gate open	200	V/µs	
Maximum peak reverse and off-state leakage current at V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>RRM</sub> , I <sub>DRM</sub>	T <sub>J</sub> = 125 °C, gate open circuit	10	mA	
Maximum peak reverse leakage current	I <sub>RRM</sub>	$T_J = 25  ^{\circ}C$	100	μΑ	
RMS isolation voltage	V <sub>ISOL</sub>	50 Hz, circuit to base, all terminals shorted, $T_J = 25$ °C, $t = 1$ s	2500	V	

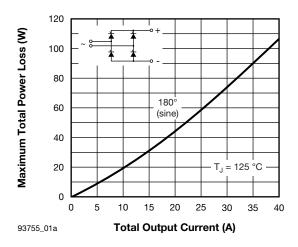
TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	$P_{GM}$			8	W
Maximum average gate power	P <sub>G(AV)</sub>			2	VV
Maximum peak gate current	I <sub>GM</sub>			2	Α
Maximum peak negative gate voltage	-V <sub>GM</sub>			10	V
		T <sub>J</sub> = - 40 °C		3	
Maximum gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C	Anode supply =	2	V
		T <sub>J</sub> = 125 °C		1	
		T <sub>J</sub> = - 40 °C	6 V resistive load	90	
Maximum gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C		60	mA
		T <sub>J</sub> = 125 °C		35	
Maximum gate voltage that will not trigger	$V_{GD}$	T 405 00 saled V 4 2 2 15 2 1		0.2	V
Maximum gate current that will not trigger	$I_{GD}$	$T_J = 125 ^{\circ}\text{C}$ , rated $V_{DRM}$ applied $2$		mA	



THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to 125	°C	
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	DC operation	1.05	K/W	
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.10	r./ vv	
Mounting torque, base to heatsink (1)			4	Nm	
Approximate weight			58	g	
Approximate weight			2.0	OZ.	
Case style			PACE-PA	AK (D-19)	

#### Note

<sup>(1)</sup> A mounting compound is recommended and the torque should be checked after a period of 3 hours to allow for the spread of the compound



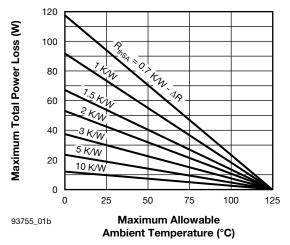


Fig. 1 - Current Ratings Nomogram (1 Module Per Heatsink)

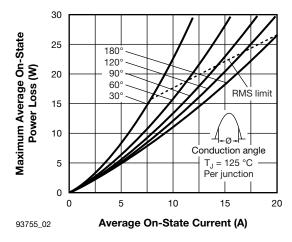


Fig. 2 - On-State Power Loss Characteristics

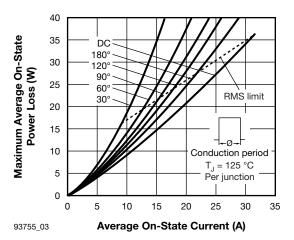


Fig. 3 - On-State Power Loss Characteristics



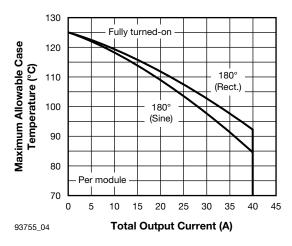


Fig. 4 - Current Ratings Characteristics

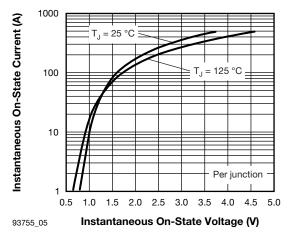


Fig. 5 - On-State Voltage Drop Characteristics

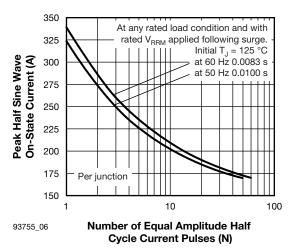


Fig. 6 - Maximum Non-Repetitive Surge Current

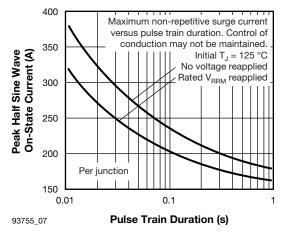


Fig. 7 - Maximum Non-Repetitive Surge Current

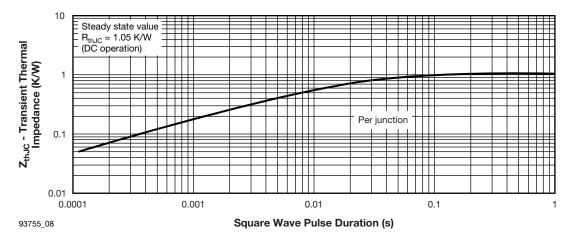


Fig. 8 - Thermal Impedance ZthJC Characteristics

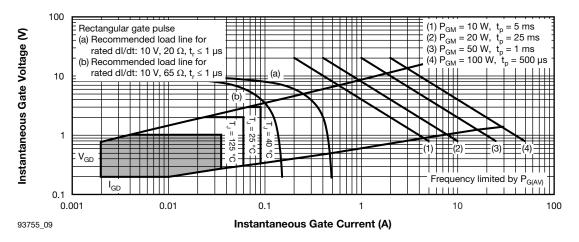
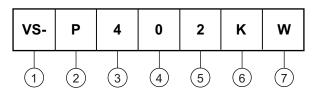


Fig. 9 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

#### Device code



- Vishay Semiconductors product
- 2 Module type
- 3 Current rating
  - 1 = 25 A DC (P100 Series)
  - 4 = 40 A DC (P400 Series)
- 4 Circuit configuration
  - 0 = Single Phase, Hybrid Bridge Common Cathode
  - 2 = Single Phase, Hybrid Bridge Doubler Connection
  - 3 = Single Phase, all SCR Bridge
- 5 Voltage code
  - 1 = 400 V
  - 2 = 600 V
  - 3 = 800 V
  - 4 = 1000 V
  - 5 = 1200 V
- 6 K = Optional Voltage Suppression
- 7 W = Optional Freewheeling Diode



CIRCUIT CONFIGURATION				
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	SCHEMATIC DIAGRAM	TERMINAL POSITIONS	
Single phase, hybrid bridge common cathode	0	AC20 (+)	AC2 G2 +	
Single phase, hybrid bridge doubler connection	2	G1 9 G2 AC2 AC1 (+)	AC1 G1 - AC2 G2 +	
Single phase, all SCR bridge	3	G3 9 G1 AC10 AC20 G4 G2 (+)	AC2 G2 - G1 G4 - AC1 G3 +	

CODING (1)						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	BASIC SERIES	WITH VOLTAGE SUPPRESSION	WITH FREEWHEELING DIODE	WITH BOTH VOLTAGE SUPPRESSION AND FREEWHEELING DIODE	
Single phase, hybrid bridge common cathode	0	P40.	P40.K	P40.W	P40.KW	
Single phase, hybrid bridge doubler connection	2	P42.	P42.K	-	-	
Single phase, all SCR bridge	3	P43.	P43.K	-	-	

#### Note

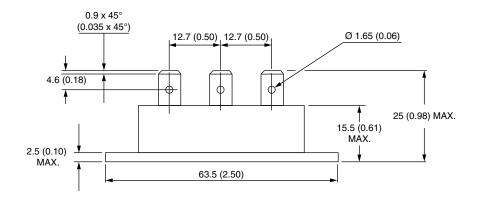
<sup>(1)</sup> To complete code refer to Voltage Ratings table, i.e.: For 600 V P40.W complete code is P402W

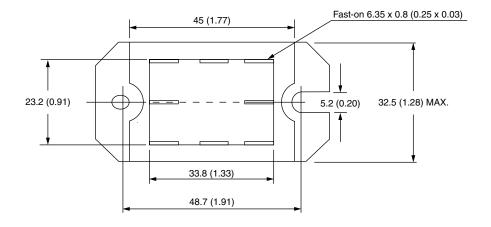
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95335



## **D-19 PACE-PAK**

### **DIMENSIONS** in millimeters (inches)







## **Legal Disclaimer Notice**

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Revision: 13-Jun-16 1 Document Number: 91000